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**DESCRIPTION**

The IF-Detector board (IF-DET) provides approximately 120 dB gain at the IF frequency, detects the audio frequencies and provides the volume squelch Hi output to the System-Audio & Squelch board (SAS). The F1 keying lead, and RX OSC control from the SAS board, compensation voltage from the exciter and the regulated +10 Volt circuits are completed through P903 and J602 on the IF-DET board.

IF-DET board 19C321662G2, G8 contains a 4-pole and a 2-pole crystal filter and operates with an IF frequency of 9.4 MHz. It is used in radios with an operating frequency of 29.7-36 MHz, 42-50 MHz and 851-870 MHz.

IF-DET board 19C321662G1, G7 also contains a 4-pole and a 2-pole crystal filter it operates with an IF frequency of 11.2 MHz and is used in radios with an operating frequency between 36-42 MHz and 66-88 MHz.

IF-DET board 19C321662G3, G9 contains two 2-pole crystal filters and operates with an IF frequency of 11.2 MHz. It is used in radios with an operating frequency of 138-174 MHz, and 406-512 MHz.

**CIRCUIT ANALYSIS**
**CRYSTAL FILTERS, IF AMP & LIMITER-DETECTOR**

The IF input from the MIF or IF Filter board is applied to a monolithic crystal filter (FL601 and FL602). The crystal filter provides additional selectivity and is followed by an impedance matching network Z601 and IF amplifier U601. The IC amplifier provides approximately 60 dB gain.

Final IF selectivity is provided by two-pole crystal filter FL603. Impedance matching network Z602 matches the output impedance of IF amplifier IC U601 to the input of two-pole crystal filter FL603. The IF amplifier output is metered at J601-1 through a metering network consisting of C612, C613, CR601 and CR602. Impedance matching network Z603 matches the output impedance of FL603 to the input of Limiter-Detector IC U602.

In addition to providing 60 dB of gain at the IF frequency, Limiter-Detector IC U602, C620, C621 and L603 comprise a quadrature phase detector to recover the audio from the IF frequency. The quadrature phase detector utilizes a 90 degree phase shift in the IF frequency to detect the audio signal. It compares the phase of the IF input at U602-4 with the same IF input frequency shifted 90 degrees at U602-2. The resultant signal varies phase linearly as the carrier signal deviates about the center frequency.

The detector output is adjusted for maximum audio output by L603 and is metered at J601-2 through R607.

**AUDIO PREAMPLIFIER**

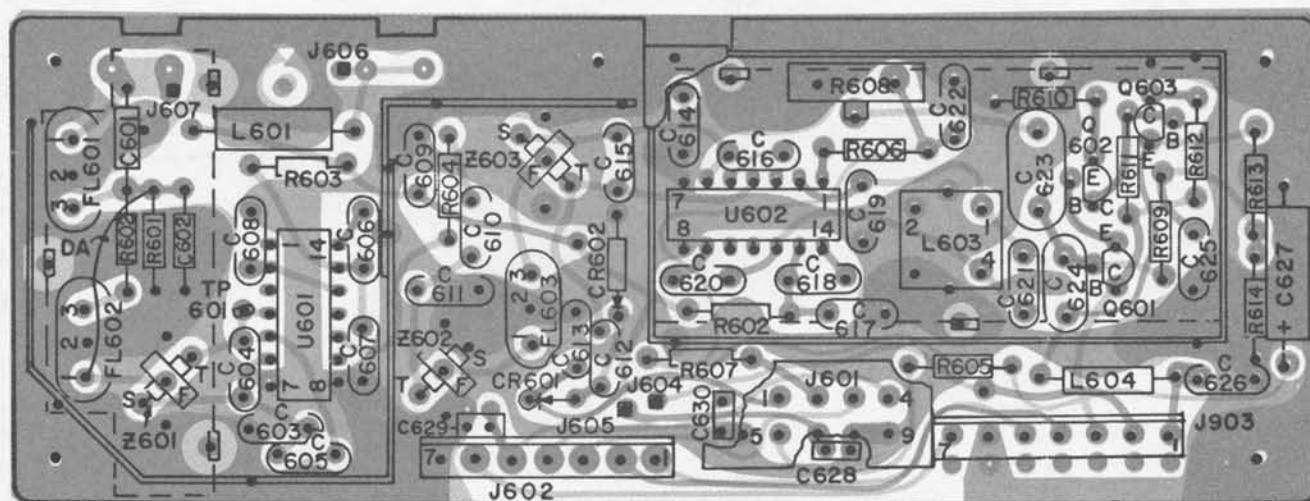
The audio preamplifier consists of transistors Q601, Q602, and Q603. It provides approximately 26 dB of gain.

The output of the Limiter-Detector is coupled to the audio preamplifier through audio level adjust control R608. R608 sets the audio input level to the preamplifier circuit.

The output of the audio preamplifier is coupled through a low pass filter (L604 and C626) to volume and squelch control circuit on the SAS board. The filter removes any IF signal remaining in the audio output of the preamplifier.

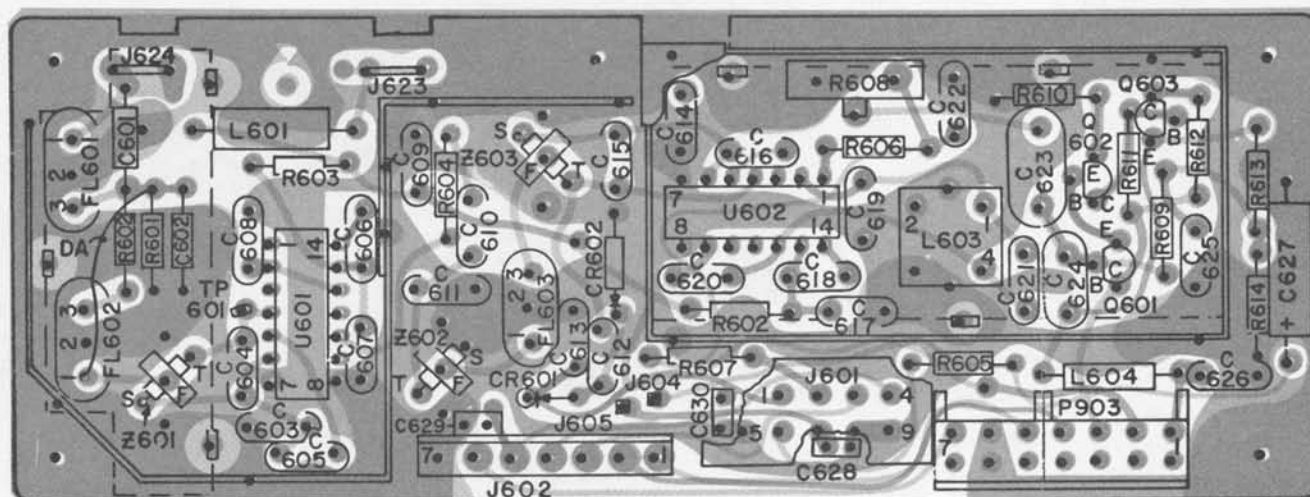
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## CUSTOM MVP/MONITOR RECEIVER



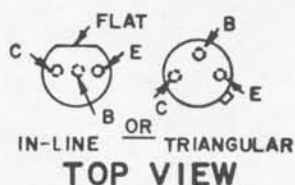
(19C327110, Sh. 2, Rev. 0)  
 (19C321673, Sh. 2, Rev. 6)  
 (19C321673, Sh. 3, Rev. 6)

## MASTR EXECUTIVE II

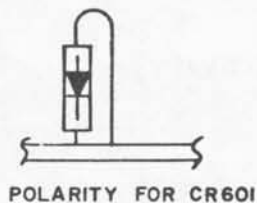


(19C327110, Sh. 1, Rev. 5)  
 (19C321673, Sh. 2, Rev. 6)  
 (19C321673, Sh. 3, Rev. 6)

LEAD IDENTIFICATION  
 FOR Q601, Q602, & Q603



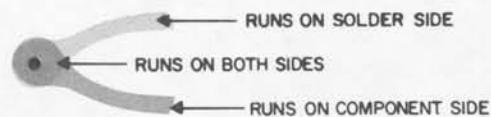
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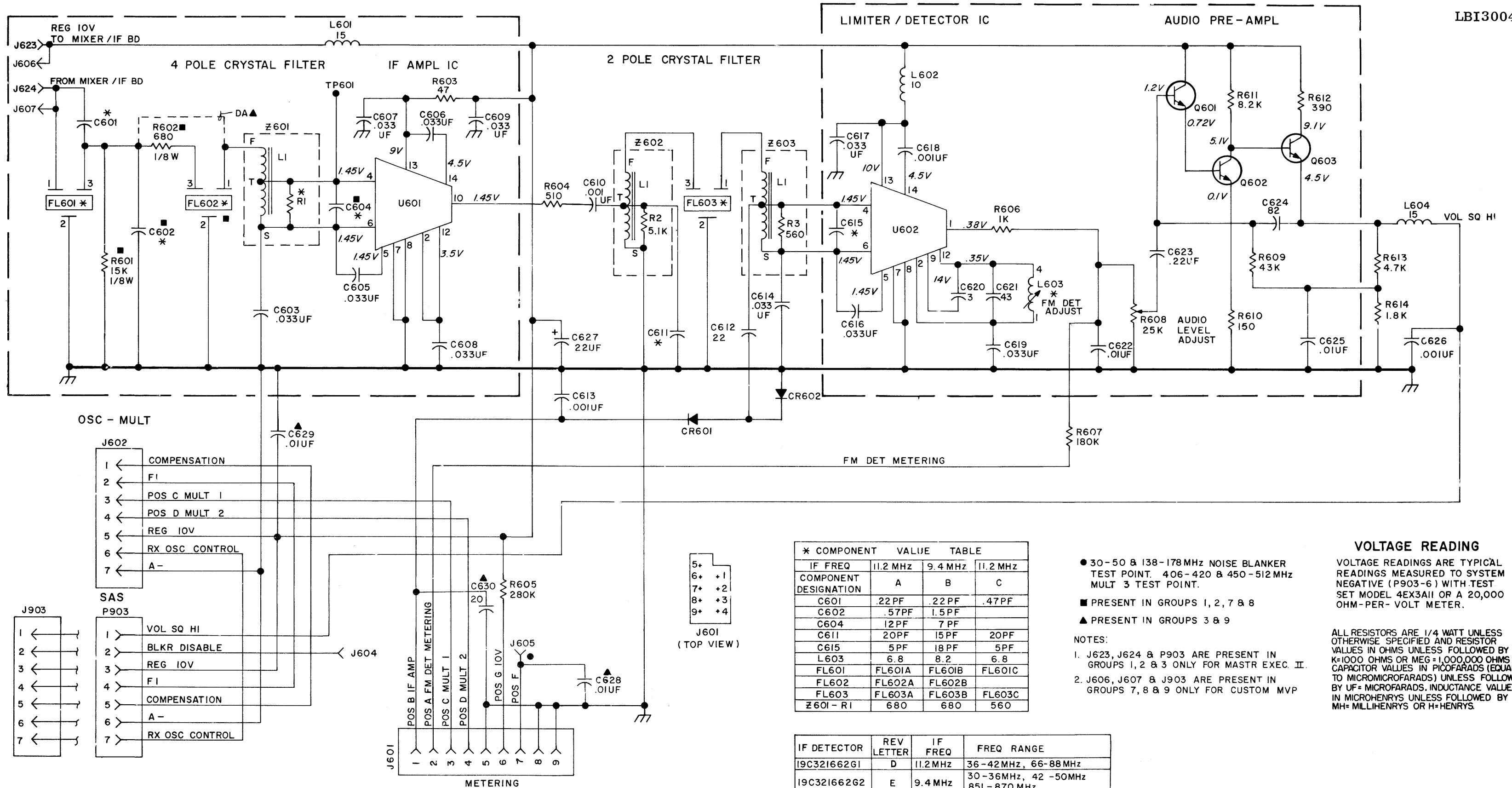


POLARITY FOR CR601

## OUTLINE DIAGRAM

IF DETECTOR BOARD  
 19C321662G1-G3, G7-G9





## SCHEMATIC DIAGRAM

IF DETECTOR BOARD  
19C321662G1-G3, G7-G9

PARTS LIST

LB130081F

IF DETECTOR BOARD

19C321661G1 36-42 MHz (IF 11.2 MHz)  
19C321661G2 30-36, 42-50 MHz (IF 9.2 MHz)  
19C321662G3 138-174, 406-512 MHz (IF 11.2 MHz)  
19C321662G7 36-42 MHz (IF 11.2 MHz)  
19C321662G8 30-36, 42-50 MHz (IF 9.2 MHz)  
19C321662G9 138-174, 406-512 MHz (IF 11.2 MHz)

SYMBOL	GE PART NO.	DESCRIPTION
----- CAPACITORS -----		
C601A and C601B	19A700013P5	Phenolic: 0.22 pF + or - 5%, 500 VDCW.
C601C	19A700013P9	Phenolic: 0.47 pF + or - 5%, 500 VDCW.
C602A	19A700013P10	Phenolic: 0.56 pF + or - 5%, 500 VDCW.
C602B	19A700013P15	Phenolic: 1.50 pF + or - 5%, 500 VDCW.
C603	19A700005P10	Polyester: 0.033 uF + or -10%, 50 VDCW.
C604A	5496219P642	Ceramic disc: 12 pF + or - 5%, 500 VDCW, temp coef -470 PPM.
C604B*	5496219P638	Ceramic disc: 7.0 pF + or - 5%, 500 VDCW, temp coef -470 PPM. In REV D and earlier:
	5496219P647	Ceramic disc: 22 pF + or - 5%, 500 VDCW, temp coef -470 PPM.
C605 thru C609	19A700005P10	Polyester: 0.033 uF + or -10%, 50 VDCW.
C610	5494481P111	Ceramic disc: 1000 pF + or - 20%, 1000 VDCW; sim to RMC Type JF Discap.
C611A	5496219P646	Ceramic disc: 20 pF + or - 5%, 500 VDCW, temp coef -470 PPM.
C611B*	5496219P644	Ceramic disc: 15 pF + or - 5%, 500 VDCW, temp coef -470 PPM. In REV D and earlier:
	5496219P649	Ceramic disc: 27 pF + or - 5%, 500 VDCW, temp coef -470 PPM.
C611C	5496219P646	Ceramic disc: 20 pF + or - 5%, 500 VDCW, temp coef -470 PPM.
C612	5496219P647	Ceramic disc: 22 pF + or - 5%, 500 VDCW, temp coef -470 PPM.
C613*	5494481P111	Ceramic disc: 1000 pF + or - 20%, 1000 VDCW; sim to RMC Type JF Discap. Earlier than REV A:
	5494481P101	Ceramic disc: 150 pF + or - 20%, 1000 VDCW; sim to RMC Type JF Discap.
C614	19A700005P10	Polyester: 0.033 uF + or -10%, 50 VDCW.
C615A	5496219P636	Ceramic disc: 5.0 pF + or - 5%, 500 VDCW, temp coef -470 PPM.
C615B*	5496219P645	Ceramic disc: 18 pF + or - 5%, 500 VDCW, temp coef -470 PPM. In REV C and D:
	5496219P649	Ceramic disc: 27 pF + or - 5%, 500 VDCW, temp coef -470 PPM. In REV B and earlier:
C615C	5496219P636	Ceramic disc: 5.0 pF + or - 5%, 500 VDCW, temp coef -470 PPM.
	19A700005P10	Polyester: 0.033 uF + or -10%, 50 VDCW.
C616 and C617		
C618	5494481P111	Ceramic disc: 1000 pF + or - 20%, 1000 VDCW; sim to RMC Type JF Discap.
C619	19A700005P10	Polyester: 0.033 uF + or -10%, 50 VDCW.

SYMBOL	GE PART NO.	DESCRIPTION
C620*	19A116656P3J1	Ceramic disc: 3 pF + or - 5%, 500 VDCW, temp coef -150 PPM. In G1, G2 of REV C and earlier: In G3 of REV E and earlier:
	5496219P334	Ceramic disc: 3.0 pF + or - 5%, 500 VDCW, temp coef -150 PPM.
C621*	19A116656P43J1	Ceramic disc: 43 pF + or - 5%, 500 VDCW, temp coef -150 PPM. In G1, G2 of REV C and earlier: In G3 of REV E and earlier:
	5496219P354	Ceramic disc: 43 pF + or - 5%, 500 VDCW, temp coef -150 PPM.
C622	19A116080P101	Polyester: 0.01 uF + or - 10%, 50 VDCW.
C623	19A116080P109	Polyester: 0.22 uF + or - 10%, 50 VDCW.
C624	19A700105P32	Mica: 82 pF + or -5%, 500 VDCW; sim to Electro Motive Type DM-15.
C625	19A116080P101	Polyester: 0.01 uF + or - 10%, 50 VDCW.
C626	5494481P111	Ceramic disc: 1000 pF + or - 20%, 1000 VDCW; sim to RMC Type JF Discap.*
C627	5496267P10	Tantalum: 22 uF + or - 20%, 15 VDCW; sim to Sprague Type 150D.
C628* and C629*	19A116192P1	Ceramic: 0.01 uF + or - 20%, 50 VDCW; sim to Erie 8121 Special. Added to G3 by REV C.
C630*	19A700219P39	Ceramic: 20 pF + or - 5%, 100 VDCW, temp coef 0 PPM. Added to G3 by REV C.
----- DIODES AND RECTIFIERS -----		
CR601 and CR602	4038056P1	Germanium.
----- FILTERS -----		
FL601A	19B219573G3	Crystal: Resonator A - 11,200.000 kHz; Resonator B - 11,196.024 kHz. Resonator A - 11,200.000 kHz; Resonator B - 11,196.024 kHz.
FL601B	19B219574G3	Crystal: Resonator A - 9400.000 kHz, Resonator B - 9396.024 kHz. Resonator A - 9400.300 kHz; Resonator B - 9396.324 kHz.
FL601C*	19B219573G6	Crystal: Resonator A - 11,200.000 kHz; Resonator B - 11,200.000 kHz.
FL602A	19B219573G1	Crystal: Resonator A - 11,200.000 kHz; Resonator B - 11,200.000 kHz. (Part of FL601A).
	FL602B	(Part of FL601B).
FL603*	19B219573G6	Crystal: Resonator A - 11,200.000 kHz; Resonator B - 11,200.000 kHz. In G1 of REV B and earlier: In G3 of REV D and earlier:
FL603B	19B219573G1	Crystal: Resonator A - 11,200.000 kHz; Resonator B - 11,200.000 kHz.
	19B219574G1	Crystal: Resonator A - 9400.000 kHz, Resonator B - 9400.000 kHz.
FL603C	19B219573G6	Crystal: Resonator A - 11,200.000 kHz; Resonator B - 11,200.000 kHz.
----- JACKS AND RECEPTACLES -----		
J601	19B219374G1	Connector, Includes:
J602	19C317957P1	Shell.
	19A116651P1	Contact, electrical; sim to Malco XO-2864.
J604 and J605	19A116659P106	Connector, printed wiring: 7 contacts rated at 5 amps; sim to Molex 09-60-1071.
	19A701785P1	Contact, electrical; sim to Molex 08-50-0404.
J606* and J607*	19A701785P1	Contact, electrical; sim to Molex 08-50-0404. Added to G1, G2 by REV B. Added to G3 by REV D.

J623 and J624	19A116975P1	Contact, electrical.
J903	19A116659P106	Connector, printed wiring: 7 contacts rated at 5 amps; sim to Molex 09-60-1071.
----- INDUCTORS -----		
L601 and L602	19A700000P25	Choke, RF: 15.0 uH + or - 10%, 1.20 ohms DC res max; sim to Jeffers 4421-9K.
L603A	19C311181G13	Coil. Includes: Tuning slug.
L603B	19C311181G14	Coil. Includes: Tuning slug.
L603C	19C311181G13	Coil. Includes: Tuning slug.
L604	19A700000P25	Choke, RF: 15.0 uH + or - 10%, 1.20 ohms DC res max; sim to Jeffers 4421-9K.
----- PLUGS -----		
P903		Connector. Includes:
19A116659P1	19A116659P1	Connector, printed wiring: 3 contacts rated at 5 amps; sim to Molex 09-52-3032.
	19A116659P15	Connector, printed wiring: 4 contacts rated at 5 amps; sim to Molex 09-52-3042.
----- TRANSISTORS -----		
Q601 thru Q603	19A115910P1	Silicon, NPN; sim to Type 2N3904.
----- RESISTORS -----		
R601	3R151P153J	Composition: 15K ohms + or - 5%, 1/8 w.
R602	3R151P681J	Composition: 680 ohms + or - 5%, 1/8 w.
R603	19A700019P21	Composition: 47 ohms + or - 5%, 1/4 w.
R604	19A143400P33	Deposited carbon: 510 ohms + or - 5%, 1/4 w.
R605	19A701250P444	Metal film: 280K ohms + or - 1%, 1/4 w.
R606	19A700019P37	Composition: 1K ohms + or - 5%, 1/4 w.
R607	19A700019P64	Composition: 0.18 megohms + or - 5%, 1/4 w.
R608	19B209358P107	Variable, carbon film: approx 800 to 25K ohms + or - 10%, 1/4 w; sim to CTS Type X-201.
R609	19A143400P56	Deposited carbon: 43K ohms + or - 5%, 1/4 w.
R610	19A700019P27	Composition: 150 ohms + or - 5%, 1/4 w.
R611	19A700019P48	Composition: 8.2K ohms + or - 5%, 1/4 w.
R612	19A700019P32	Composition: 390 ohms + or - 5%, 1/4 w.
R613	19A700019P45	Composition: 4.7K ohms + or - 5%, 1/4 w.
R614	19A700019P40	Composition: 1.8K ohms + or - 5%, 1/4 w.
----- TEST POINTS -----		
TP601	19A701622P1	Cotter pin.
----- INTEGRATED CIRCUITS -----		
U601 and U602	19A116445P1	Integrated circuit, linear: sim to ULN2111.
----- NETWORKS -----		
Z601A	19B226649G1	Coil assembly. Includes:
R1	3R152P681J	Resistor, composition: 680 ohms + or - 5%, 1/4 w.
Z601B*	19B226649G4	Coil assembly. Includes:
R1	3R152P681J	Resistor, composition: 680 ohms + or - 5%, 1/4 w. In REV D and earlier:
R1	19B226649G1	Coil assembly. Includes:
	3R152P681J	Resistor, composition: 680 ohms + or - 5%, 1/4 w.
Z601C	19B226649G3	Coil assembly. Includes:
R3	3R152P561J	Resistor, composition: 560 ohms + or - 5%, 1/4 w.
Z602A	19B226649G2	Coil assembly. Includes:
R2	3R152P512J	Resistor, composition: 5.1K ohms + or - 5%, 1/4 w.

Z602B*	19B226649G5	Coil assembly. Includes:
R2	3R152P512J	Resistor, composition: 5.1K ohms + or - 5%, 1/4 w. In REV D and earlier:
R2	19B226649G2	Coil assembly. Includes:
	3R152P512J	Resistor, composition: 5.1K ohms + or - 5%, 1/4 w.
Z602C	19B226649G2	Coil assembly. Includes:
R2	3R152P512J	Resistor, composition: 5.1K ohms + or - 5%, 1/4 w.
Z603A	19B226649G3	Coil assembly. Includes:
R3	3R152P561J	Resistor, composition: 560 ohms + or - 5%, 1/4 w.
Z603B*	19B226649G6	Coil assembly. Includes:
R3	3R152P561J	Resistor, composition: 560 ohms + or - 5%, 1/4 w. In REV D and earlier:
R3	19B226649G3	Coil assembly. Includes:
	3R152P561J	Resistor, composition: 560 ohms + or - 5%, 1/4 w.
----- MISCELLANEOUS -----		
19B226648G1	19B226648G1	Shield. (Located around FL601, FL602).
	19B219571G1	Shield. (Located under Z601, J624 on opposite side of component board).
19B219554G1	19B219554G1	Can. (Located around U602, Q603).
	19B219555P1	Cover. (Used with 19B219554G1 Can).
19B219727G1	19B219727G1	Shield. (Located under 19B219554G1 Can).
	19A116428P4	Contact, electrical: sim to AMP 86031-1 (strip form). (Used with shields on bottom of circuit board).
19C327289P1		Bottom Cover. (IF Detector- 25-512 MHz).
19C321744P1		Bottom Cover. (IF Detector- 806-870 MHz).

PRODUCTION CHANGES

Changes in the equipment to improve performance or to simplify circuits are identified by a "Revision Letter", which is stamped after the model number of the unit. The revision stamped on the unit includes all previous revisions. Refer to the Parts List for descriptions of parts affected by these revisions.

REV. A - IF Detector Board 19C321662G1-3  
To improve IF stability.  
Changed C613.

REV. C - IF Detector Board 19C321662G3  
To improve IF tuning. Added C628, C629 and C630.

REV. B - IF Detector Board 19C321662G1, 2

REV. D - IF Detector Board 19C321662G3  
To make compatible for Custom MVP applications.  
Added J606 and J607.

REV. C - IF Detector Board 19C321662G1

REV. E - IF Detector Board 19C321662G3  
To improve operation. Changed FL601C and FL603A.

REV. C - IF Detector Board 19C321662G2  
To improve IF response. Changed C615B.

REV. D - IF Detector Board 19C321662G1, 2

REV. F - IF Detector Board 19C321662G3  
To improve operation. Changed C620 and C621.

REV. E - IF Detector Board 19C321662G2  
To improve IF response. Changed C604B, C611B, C615B, Z601, Z602 and Z603.

## ADDENDUM #1 TO LBI30049F

This addendum contains information on IF-Detector board 19D432538G1-G6. The IF-Det board used tuneable IF transformers to facilitate alignment and troubleshooting. Changes in the IF alignment and circuit analysis of the IF-Det board are contained in this addendum.

### DESCRIPTION

The IF-Detector board (IF-DET) provides approximately 120 dB gain at the IF frequency, detects the audio frequencies and provides the volume squelch Hi output to the System-Audio & Squelch board (SAS). The F1 keying lead, and RX OSC control from the SAS board, compensation voltage from the exciter and the regulated +10 Volt circuits are completed through P903/J903 and J602 on the IF-DET board.

IF-DET board 19D432538G2 and G5 contains a 4-pole and a 2-pole crystal filter and operates with an IF frequency of 9.4 MHz. It is used in radios with an operating frequency of 29.7-36 MHz, 42-50 MHz and 851-870 MHz.

IF-DET board 19D432538G1 and G4 also contains a 4-pole and a 2-pole crystal filter. It operates with an IF frequency of 11.2 MHz and is used in radios with an operating frequency between 36-42 MHz and 66-88 MHz.

IF-DET board 19D432538G3 and G6 contains two 2-pole crystal filters and operates with an IF frequency of 11.2 MHz. It is used in radios with an operating frequency of 138-174 MHz, and 406-512 MHz.

### CIRCUIT ANALYSIS

#### CRYSTAL FILTERS, IF AMP & LIMITER-DETECTOR

The IF input from the MIF or IF Filter board is applied to monolithic crystal filter FL601 and FL602. The crystal filter provides additional selectivity and is followed by a tuneable impedance matching network (T601) and IF amplifier U601. The IC amplifier provides approximately 60 dB gain.

Final IF selectivity is provided by two-pole crystal filter FL603. A tuneable impedance matching network T602 matches the output impedance of IF amplifier IC U601 to the input of crystal filter FL603. The IF amplifier output is metered at J601-1 through a metering network consisting of

C612, C613, CR601 and CR602. Tuneable impedance matching network T603 matches the output impedance of FL603 to the input of Limiter-Detector IC U602.

In addition to providing 60 dB of gain at the IF frequency, Limiter-Detector IC U602, C620, C621 and L603 comprise a quadrature phase detector to recover the audio from the IF frequency. The quadrature phase detector utilizes a 90 degree phase shift in the IF frequency to detect the audio signal. It compares the phase of the IF input at U602-4 with the same IF input frequency shifted 90 degrees at U602-2. The resultant signal varies phase linearly as the carrier signal deviates about the center frequency.

The detector output is adjusted for maximum audio output by FM DET ADJUST T604, and is metered at J601-2 through R607.

#### AUDIO PREAMPLIFIER

The audio preamplifier consists of transistors Q601, Q602, and Q603. It provides approximately 26 dB of gain.

The output of the Limiter-Detector is coupled to the audio preamplifier through audio level adjust control R608. R608 sets the audio input level to the preamplifier circuit.

The output of the audio preamplifier is coupled through a low pass filter (L604 and C626) to volume and squelch control circuit on the SAS board. The filter removes any IF signal remaining in the audio output of the preamplifier.

### ALIGNMENT CHANGES

#### FM DETECTOR

When adjusting the FM detector, substitute T604 for L603 in the Complete Receiver Alignment.

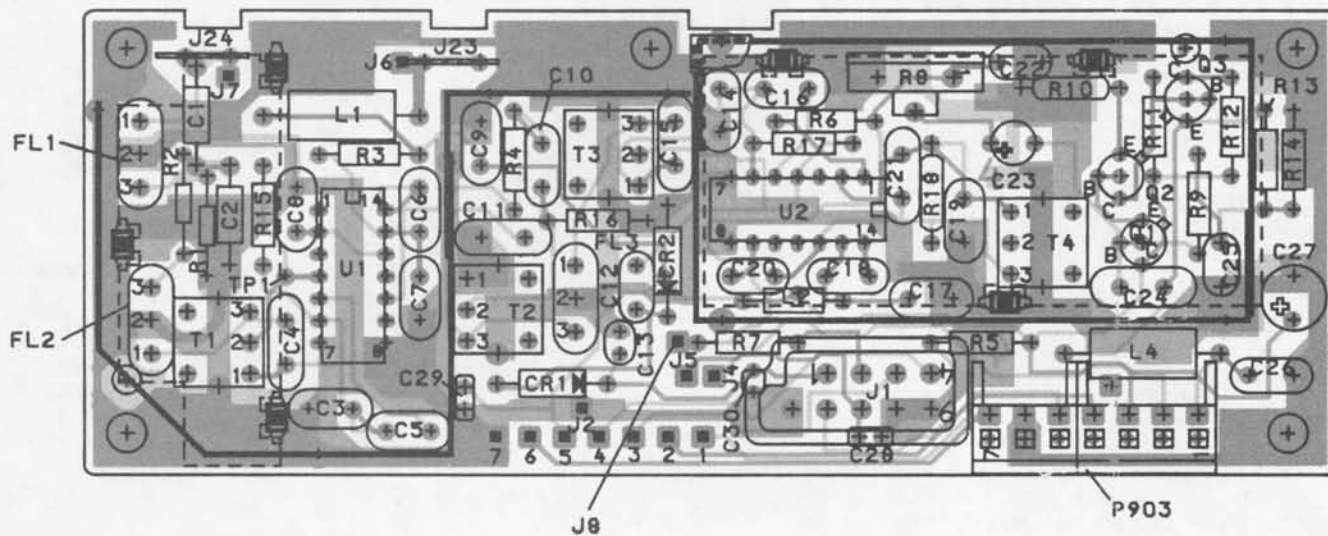
#### IF-DETECTOR

After completing the Mixer-IF alignment steps, set cores of T601, T602 and T603 to top of coil form. Then tune T601, T602 and T603 for double trace as shown on scope pattern in the Complete Receiver Alignment. Reduce generator output as required to keep full waveform on scope.

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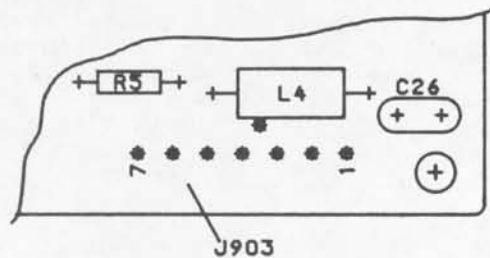


# MASTR EXECUTIVE II

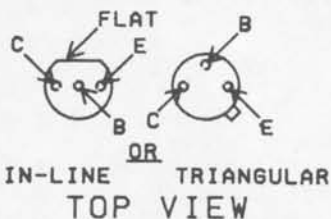


(19D432539, Rev. 5)  
(19A143462, Sh. 1, Rev. 4)  
(19A143462, Sh. 2, Rev. 4)

## CUSTOM



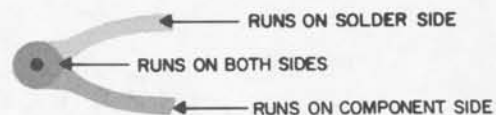
LEAD IDENTIFICATION  
FOR Q1, Q2 & Q3



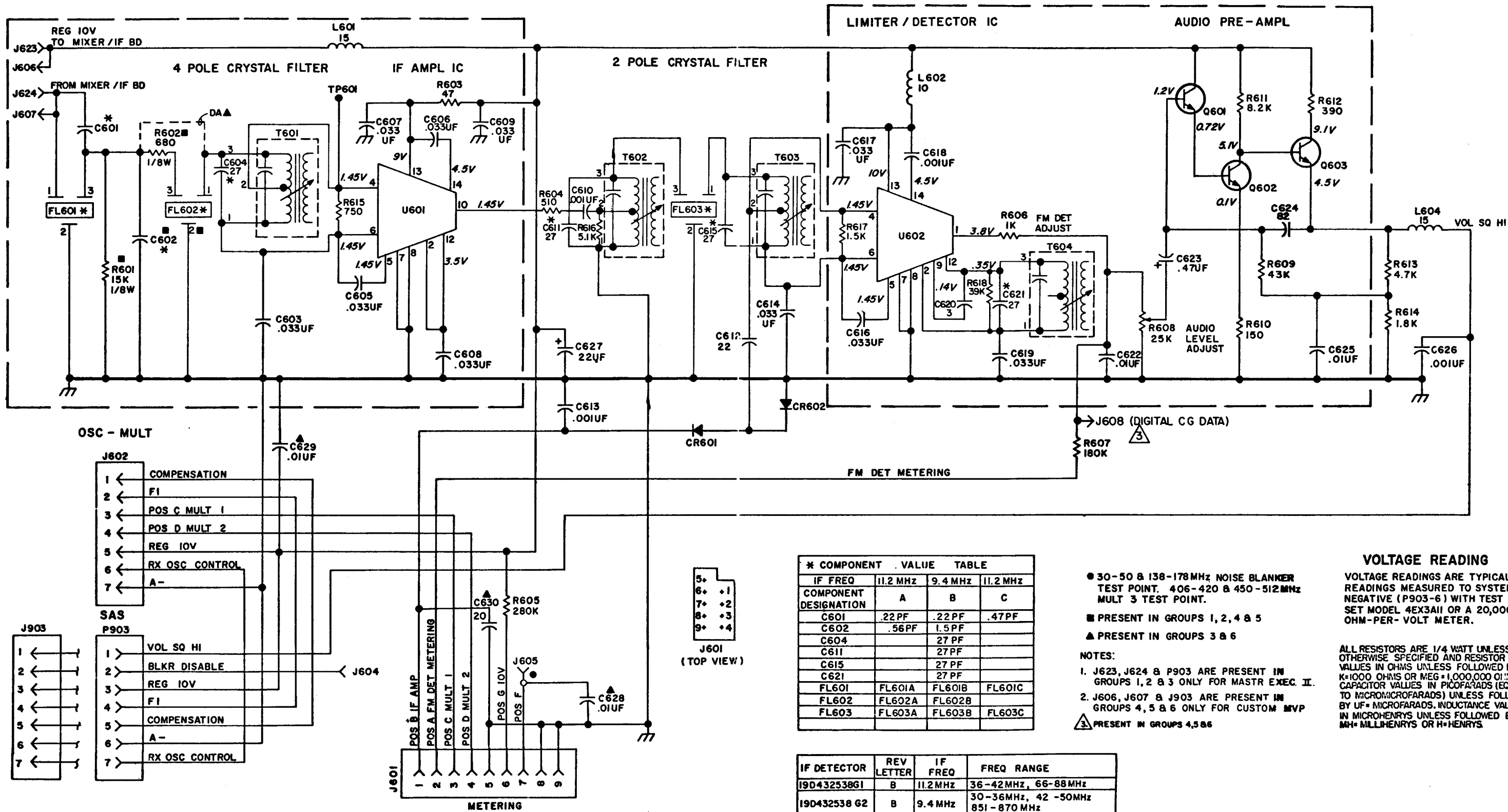
NOTE: LEAD ARRANGEMENT, AND NOT  
CASE SHAPE, IS DETERMINING  
FACTOR FOR LEAD IDENTIFICATION.

## OUTLINE DIAGRAM

IF DETECTOR BOARD  
19D432538G1-G6







SCHEMATIC DIAGRAM

IF DETECTOR BOARD  
19D432538G1-G6

PARTS LIST

IF DETECTOR BOARD  
19D432538G1 11.2 MHz MASTR EXEC II - REV A  
19D432538G2 9.2 MHz MASTR EXEC II - REV A  
19D432538G3 11.2 MHz MASTR EXEC II - REV A  
19D432538G4 11.2 MHz CUSTOM MVP - REV C  
19D432538G5 9.2 MHz CUSTOM MVP - REV C  
19D432538G6 11.2 MHz CUSTOM MVP - REV C  
ISSUE 2

SYMBOL	GE PART NO.	DESCRIPTION
----- CAPACITORS -----		
C601A and C601B	19A700013P5	Phenolic: 0.22 pF ±5%, 500 VDCW.
C601C	19A700013P9	Phenolic: 0.47 pF ±5%, 500 VDCW.
C602A	19A700013P10	Phenolic: 0.56 pF ±5%, 500 VDCW.
C602B	19A700013P15	Phenolic: 1.50 pF ±5%, 500 VDCW.
C603	19A700234P10	Polyester: 0.033 uF ±10%, 50 VDCW.
C604	19A701624P118	Ceramic: 27 pF ±5%, 500 VDCW, temp coef -80 PPM.
C605 thru C609	19A700234P10	Polyester: 0.033 uF ±10%, 50 VDCW.
C610	19A701602P19	Ceramic: 1000 pF ±20%, 1000 VDCW; sim to RMC Type JF Discap.
C611	19A701624P118	Ceramic: 27 pF ±5%, 500 VDCW, temp coef -80 PPM.
C612	19A701624P516	Ceramic: 22 pF ±5%, 500 VDCW, temp coef -470 PPM.
C613	19A116192P13	Ceramic: 1000 pF ±10%, 50 VDCW; sim to Erie 8121-A050-W5R-102K.
C614	19A700234P10	Polyester: 0.033 uF ±10%, 50 VDCW.
C615	19A701624P118	Ceramic: 27 pF ±5%, 500 VDCW, temp coef -80 PPM.
C616 and C617	19A700234P10	Polyester: 0.033 uF ±10%, 50 VDCW.
C618	19A701602P19	Ceramic: 1000 pF ±20%, 1000 VDCW; sim to RMC Type JF Discap.
C619	19A700234P10	Polyester: 0.033 uF ±10%, 50 VDCW.
C620	19A701624P201	Ceramic: 3.0 pF ±0.5 pF, 500 VDCW, temp coef -150 PPM.
C621	19A701624P118	Ceramic: 27 pF ±5%, 500 VDCW, temp coef -80 PPM.
C622	19A700234P7	Polyester: 0.01 uF ±10%, 50 VDCW.
C623	19A701534P3	Tantalum: 0.47 uF ±20%, 35 VDCW.
C624	19A700105P32	Mica: 82 pF ±5%, 500 VDCW.
C625	19A700234P7	Polyester: 0.01 uF ±10%, 50 VDCW.
C626	19A701602P19	Ceramic: 1000 pF ±20%, 1000 VDCW; sim to RMC Type JF Discap.
C627	19A701534P8	Tantalum: 22 uF ±20%, 16 VDCW.
C628 and C629	19A116192P1	Ceramic: 0.01 uF ±20%, 50 VDCW; sim to Erie 8121 Special.
C630	19A116114P39	Ceramic: 20 pF ±5%, 100 VDCW; temp coef 0 PPM.
----- DIODES AND RECTIFIERS -----		
CR601 and CR602	4038056P1	Germanium.
----- FILTERS -----		
FL601A	19B219573G3	Crystal: Resonator A - 11,200.000 kHz; Resonator B - 11,196.024 kHz; Resonator A - 11,200.000 kHz; Resonator B - 11,196.024 kHz.
FL601B	19B219574G3	Crystal: Resonator A - 9400.300 kHz, Resonator B - 9396.324 kHz; Resonator A - 9400.300 kHz, Resonator B - 9396.324 kHz.
FL601C*	19B219573G6	Crystal: Resonator A - 11,200.000 kHz; Resonator B - 11,200.000 kHz.  In G1 of REV B and earlier: In G3 of REV D and earlier:
	19B219573G1	Crystal: Resonator A - 11,200.000 kHz; Resonator B - 11,200.000 kHz.

SYMBOL	GE PART NO.	DESCRIPTION
FL602A		(Part of FL601A).
FL603A		(Part of FL601B).
FL603A	19B219573G6	Crystal: Resonator A - 11,200.000 kHz; Resonator B - 11,200.000 kHz.
FL603B	19B219574G1	Crystal: Resonator A - 9400.300 kHz, Resonator B - 9400.300 kHz.
FL603C	19B219573G6	Crystal: Resonator A - 11,200.000 kHz; Resonator B - 11,200.000 kHz.
----- JACKS AND RECEPTACLES -----		
J601	19B219374G1	Connector. Includes:  Shell.
	19C317957P1	Connector, Includes: Contact, electrical.
J602	19A701785P2	Contact, electrical; sim to Molex -08-50-0404.
J604 thru J607	19A701785P2	Contact, electrical; sim to Molex -08-50-0404.
J623 and J624	19A116975P1	Contact, electrical.
J903	19A701785P2	Contact, electrical; sim to Molex -08-50-0404.
----- INDUCTORS -----		
L601	19A700000P25	Choke, RF: 15.0 uH ±10%, 1.20 ohms DC res max; sim to Jeffers 4421-8K.
L602	19A700024P25	Coil, RF: 10.0 uH ±10%, 3.70 ohms DC res max.
L604	19A700000P25	Choke, RF: 15.0 uH ±10%, 1.20 ohms DC res max; sim to Jeffers 4421-8K.
----- PLUGS -----		
P903		Connector. Includes:  19A116659P1 Connector, printed wiring: 3 contacts rated at 5 amps; sim to Molex 09-52-3032.  19A116659P15 Connector, printed wiring: 4 contacts rated at 5 amps; sim to Molex 09-52-3042.
Q601 thru Q603	19A115910P1	Silicon, NPN; sim to Type 2N3904.
----- RESISTORS -----		
R601	3R151P153J	Composition: 15K ohms ±5%, 1/8 w.
R602	3R151P681J	Composition: 680 ohms ±5%, 1/8 w.
R603	19A700019P21	Deposited carbon: 47 ohms ±5%, 1/4 w.
R604	19A143400P33	Deposited carbon: 510 ohms ±5%, 1/4 w.
R605	19A701250P444	Metal film: 280K ohms ±1%, 1/4 w.
R606	19A700019P37	Deposited carbon: 1K ohms ±5%, 1/4 w.
R607	19A700019P64	Deposited carbon: 0.18 megohms ±5%, 1/4 w.
R608	19B209358P107	Variable, carbon film: approx 800 to 25K ohms ±10%, 1/4 w; sim to CTS Type X-201.
R609	19A143400P56	Deposited carbon: 43K ohms ±5%, 1/4 w.
R610	19A700019P27	Deposited carbon: 150 ohms ±5%, 1/4 w.
R611	19A700019P48	Deposited carbon: 8.2K ohms ±5%, 1/4 w.
R612	19A700019P32	Deposited carbon: 390 ohms ±5%, 1/4 w.
R613	19A700019P45	Deposited carbon: 4.7K ohms ±5%, 1/4 w.
R614	19A700019P40	Deposited carbon: 1.8K ohms ±5%, 1/4 w.
R615	19A143400P35	Deposited carbon: 750 ohms ±5%, 1/4 w.
R616	19A143400P45	Deposited carbon: 5.1K ohms ±5%, 1/4 w.
R617	19A700019P39	Deposited carbon: 1.5K ohms ±5%, 1/4 w.
R618	19A700019P56	Deposited carbon: 39K ohms ±5%, 1/4 w.

SYMBOL	GE PART NO.	DESCRIPTION
----- TRANSFORMERS -----		
T601 thru T604	19A134747P2	Transformer, IF: resonant freq. 10.7 MHz; sim to TOKO Inc. 154 PC-470073N3.
----- TEST POINTS -----		
TP601	19A701622P1	Cotter pin.
----- INTEGRATED CIRCUITS -----		
U601 and U602	19A116445P1	Integrated circuit, linear: sim to ULN2111.
----- MISCELLANEOUS -----		
	19B226648G1	Shield. (Located around FL601, FL602).
	19B219571G1	Shield. (Located under Z601, J624 on opposite side of component board).
	19B219554G1	Can. (Located around U602, Q603).
	19B219555P1	Cover. (Used with 19B219554G1 can).
	19B219727G1	Shield. (Located under 19B219554G1 can).
	19A116428P4	Ground tab; sim to AMP 86031-1 (Strip Form). (Used with shields on bottom of circuit board).

PRODUCTION CHANGES

Changes in the equipment to improve performance or to simplify circuits are identified by a "Revision Letter," which is stamped after the model number of the unit. The revision stamped on the unit includes all previous revisions. Refer to the Parts List for descriptions of parts affected by these revisions.

- REV. A - IF Detector Board 19D423538G1-G6  
To improve operation at temperature extremes. Added R618.
- REV. B - To correct frequency response at 100 Hz. Change C623.  
C623 was: 19A116080P109, Polyester: 0.22 uF ±10%, 50 VDCW.
- REV. C - To provide an electrical connection for Digital Channel Guard.  
Added J608.